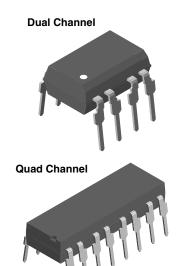
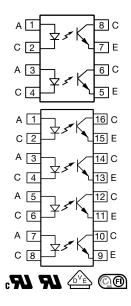


i179015-1

Vishay Semiconductors

Optocoupler, Phototransistor Output, (Dual, Quad Channel), 110 °C Rated





LINKS TO ADDITIONAL RESOURCES



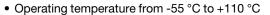
DESCRIPTION

The ILD1615, ILQ1615 are multi-channel 110 $^{\circ}$ C rated phototransistor optocouplers that use GaAs IRLED emitters and high gain NPN phototransistors. These devices are constructed using over/under leadframe optical coupling and double molded insulation technology resulting a withstand test voltage of 7500 $V_{AC\ PEAK}$ and a working voltage of 1700 V_{RMS} .

The binned min. / max. and linear CTR characteristics make these devices well suited for DC or AC voltage detection. Eliminating the phototransistor base connection provides added electrical noise immunity from the transients found in many industrial control environments.

Because of guaranteed maximum non-saturated and saturated switching characteristics, the ILD1615, ILQ1615 can be used in medium speed data I/O and control systems. The binned min. / max. CTR specification allow easy worst case interface calculations for both level detection and switching applications. Interfacing with a CMOS logic is enhanced by the guaranteed CTR at $I_F = 1.0$ mA.

FEATURES





RoHS

- Identical channel to channel footprint
- Dual and quad packages feature:
 - Reduced board space
 - Lower pin and parts count
 - Better channel to channel CTR match
 - Improved common mode rejection
- Isolation test voltage, 5300 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AGENCY APPROVALS

- <u>UL 1577</u>
- cUL
- DIN EN 60747-5-5 (VDE 0884), available with option 1
- FIMKO



ORDERING INFORMATION				
L x 1 PART NUM		CTR BIN		
	DUAL CHANNEL	QUAD CHANNEL		
AGENCY CERTIFIED / DACKAGE				
AGENCY CERTIFIED / PACKAGE	сті	R (%)		
AGENCY CERTIFIED / PACKAGE UL, cUL, FIMKO	160 to 320	160 to 320		
		` ,		

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Peak reverse voltage		V _R	6.0	V
Forward current		l _F	60	mA
Surge current		I _{FSM}	1.5	А
Power dissipation		P _{diss}	100	mW
Derate linearly from 25 °C			1.0	mW/°C
ОUТРUТ				
Collector emitter breakdown voltage		BV _{CEO}	70	V
Emitter collector breakdown voltage		BV _{ECO}	7.0	V
0.11		I _C	50	mA
Collector current	t < 1.0 ms	I _C	100	mA
Power dissipation		P _{diss}	150	mW
Derate linearly from 25 °C			1.5	mW/°C
COUPLER				
Storage temperature		T _{stg}	-55 to +150	°C
Operating temperature		T _{amb}	-55 to +110	°C
Soldering temperature (1)	2.0 mm distance from case bottom	T _{sld}	260	°C
Package power dissipation ILD1615			400	mW
Derate linearly from 25 °C			5.33	mW/°C
Package power dissipation ILQ1615			500	mW
Derate linearly from 25 °C			6.67	mW/°C

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to wave profile for soldering conditions for through hole devices



ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I _F = 10 mA	V_{F}	1.0	1.15	1.3	V		
Breakdown voltage	I _R = 10 μA	V_{BR}	6.0	30	-	V		
Reverse current	$V_{R} = 6.0 \text{ V}$	I _R	-	0.01	10	μA		
Capacitance	$V_R = 0 V, f = 1.0 MHz$	Co	-	25	-	pF		
OUTPUT								
Collector emitter capacitance	$V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$	C _{CE}	-	6.8	-	pF		
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}	-	5.0	100	nA		
Collector emitter breakdown voltage	$I_{CE} = 0.5 \text{ mA}$	BV _{CEO}	70	-	-	V		
Emitter collector breakdown voltage	$I_{E} = 0.1 \text{ mA}$	BV _{ECO}	7.0	-	-	V		
PACKAGE TRANSFER CHARACTERI	STICS							
Channel/channel CTR match	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	CTRX/CTRY	1 to 1	-	2 to 1			
COUPLER								
Capacitance (input to output)	$V_{IO} = 0 \text{ V, f} = 1.0 \text{ MHz}$	C _{IO}	-	0.8	-	pF		
Insulation resistance	V _{IO} = 500 V, T _A = 25 °C	R _S	10 ¹²	10 ¹⁴	-	Ω		
Channel to channel isolation			500	-	-	V _{AC}		

Note

Minimum and maximum values are tested requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_E = 1.0 \text{ mA}, V_{CE} = 0.4 \text{ V}$	ILD1615-4	CTD	-	100	-	%
(collector emitter saturated)	$I_F = 1.0 \text{ mA}, V_{CE} = 0.4 \text{ V}$	ILQ1615-4	CTR _{CEsat}				%
Current transfer ratio (collector emitter)	I _F = 10 mA, V _{CE} = 5.0 V	ILD1615-4	CTR _{CE}	160	200	320	%
		ILQ1615-4					70
	1 10 m/s \/ 50 \/	ILD1615-4	- CTR _{CE}	CTR _{CE} 56	90	-	0/
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILQ1615-4					%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED						
Turn-on time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{on}	-	3.0	-	μs
Rise time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _r	=	2.0	-	μs
Turn-off time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{off}	=	2.3	-	μs
Fall time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _f	-	2.0	-	μs
Propagation H to L	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{PHL}	=	1.1	-	μs
Propagation L to H	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{PLH}	=	2.5	-	μs
SATURATED						
Turn-on time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _{on}	=	6.0	-	μs
Rise time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _r	=	4.6	-	μs
Turn-off time	$I_F = 5.0$ mA, $V_{CC} = 5.0$ V, $R_L = 1.0$ k Ω , $V_{HT} = 1.5$ V	t _{off}	-	25	-	μs
Fall time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _f	-	15		μs
Propagation H to L	$I_F = 5.0$ mA, $V_{CC} = 5.0$ V, $R_L = 1.0$ k Ω , $V_{HT} = 1.5$ V	t _{PHL}	-	5.4	-	μs
Propagation L to H	$I_F = 5.0$ mA, $V_{CC} = 5.0$ V, $R_L = 1.0$ k Ω , $V_{HT} = 1.5$ V	t _{PLH}	-	7.4	-	μs



COMMON MODE TRANSIENT IMMUNITY (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode rejection output high	V_{CM} = 50 V_{P-P} , R_L = 1.0 $k\Omega$, I_F = 0 mA	CM _H	-	5000	-	V/µs
Common mode rejection output low	V_{CM} = 50 V_{P-P} , R_L = 1.0 $k\Omega$, I_F = 10 mA	CML	-	5000	-	V/µs
Common mode coupling capacitance		C _{CM}	-	0.01	-	pF

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification	According to IEC 68 part 1		55 / 110 / 21			
Comparative tracking index		CTI	175			
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V_{RMS}		
Maximum transient isolation voltage		V _{IOTM}	10 000	V _{peak}		
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}		
Leadella constate con	$V_{IO} = 500 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω		
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω		
Output safety power		P _{SO}	400	mW		
Input safety current		I _{SI}	275	mA		
Safety temperature		T _S	175	°C		
Creepage distance			≥ 7	mm		
Clearance distance			≥ 7	mm		
Insulation thickness		DTI	≥ 0.4	mm		

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

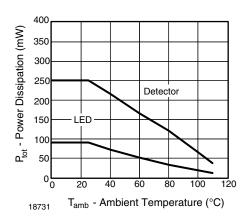


Fig. 1 - Permissible Power Dissipation vs. Temperature Non-Saturation Operation

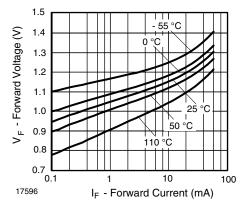


Fig. 2 - Forward Voltage vs. Forward Current

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.



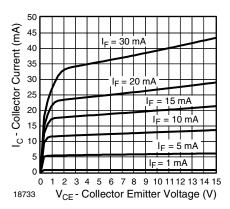


Fig. 3 - Collector Current vs. Collector Emitter Voltage

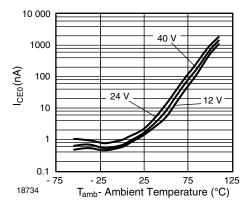


Fig. 4 - Collector to Emitter Dark Current vs. Ambient Temperature

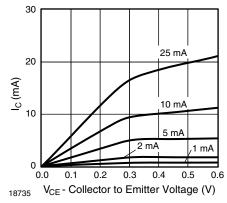


Fig. 5 - Normalized Current vs. Collector Emitter Saturation Voltage

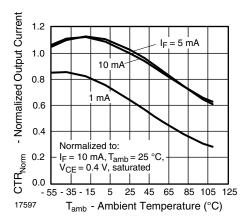


Fig. 6 - Normalized Current Transfer Ratio vs. Ambient Temperature

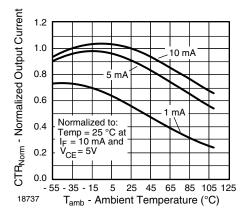


Fig. 7 - Normalized CTR vs. Temperature

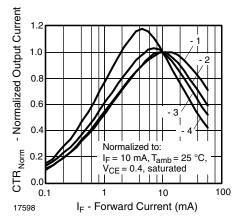


Fig. 8 - Normalized CTR vs. Forward Current



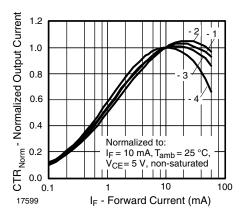


Fig. 9 - Normalized CTR vs. Forward Current

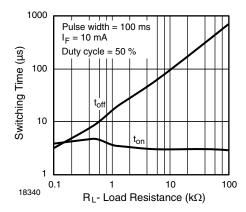


Fig. 10 - Forward Resistance vs. Forward Current

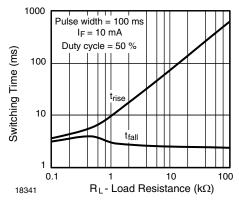
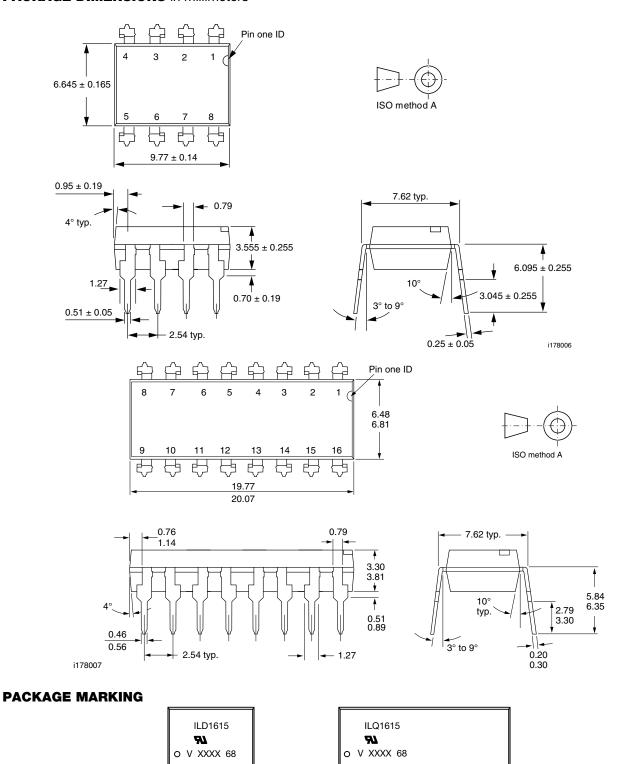


Fig. 11 - Forward Resistance vs. Forward Current



PACKAGE DIMENSIONS in millimeters



Note

• XXXX = LMC (lot marking code)



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